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EEC603

(Following Paper ID and Roll No. to be filled in your Answer Book)

PAPER ID : 131603 Roll No. 

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**B.Tech.**

(SEM. VI) THEORY EXAMINATION 2013-14

**MICROWAVE ENGINEERING***Time : 3 Hours**Total Marks : 100***Note :-** Attempt **all** questions. Each question carries equal marks.

1. Attempt any **four** parts of the following : **(5×4=20)**
- Use Maxwell's equations to show that TEM mode cannot exist in the hollow waveguide.
  - An airfilled rectangular waveguide with a cross section  $2 \times 1$  cms transports energy in the  $TE_{10}$  mode at a rate of 0.5 hp. The impressed frequency is 30 GHz. What is the peak value of electric field in the guide ?
  - Show that  $TM_{10}$  and  $TM_{01}$  modes in rectangular waveguide do not exist.
  - A  $TE_{11}$  mode of 10 GHz is propagating in air filled rectangular waveguide. The magnetic field in the z direction is given by :

$$H_z = H_0 \cos\left(\frac{\pi x}{\sqrt{6}}\right) \cos\left(\frac{\pi y}{\sqrt{6}}\right) \frac{A}{m}$$

The phase constant  $\beta = 1.0475 \frac{\text{rad}}{\text{cm}}$  (x, y, a and b are in cms).

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Find– Cutoff frequency, phase velocity in guide, guided wavelength and magnetic field intensity in the y direction.

- (e) A circular waveguide has a cutoff frequency of 7 GHz in the dominant mode ( $X'_{11} = 1.841$ ), find –
- (i) inside diameter of guide if it is airfilled
  - (ii) inside dimension of guide if it is filled with a dielectric of dielectric constant  $\epsilon_r = 2.1$  and  $\mu_r = 1$ .
- (f) Write short note on microstrip transmission line.

2. Attempt any **four** parts of the following : **(5×4=20)**

- (a) Show that a rectangular cavity may be viewed as a rectangular waveguide shorted at both ends. Also find the resonance condition.
- (b) A rectangular cavity resonator has dimension  $a = 7.5$  cm,  $b = 4$  cm and  $d = 16$  cm, calculate – the resonant frequency of dominant mode, cutoff wave number and phase constant.
- (c) Prove that it is impossible for a general three-port junction (for example E-plane tee) of arbitrary symmetry to present matched impedance at all three arms.
- (d) What is Faraday Rotation ? How it is used in designing microwave components ?
- (e) Derive the schematic diagram of four port microwave circulator and derive its S-matrix.
- (f) Incident power for a 30 dB coupler is 560 MW. Calculate the power in the main arm and in auxiliary arm.

3. Attempt any **two** parts of the following : (10×2=20)

- (a) What are the limitations of conventional active devices at microwave frequencies ? Explain in detail.
- (b) What is Travelling Wave Tube ? Explain the principle of operation and construction of T.W.T. Also write its limitations.

(c) A two cavity Klystron amplifier has the following parameters :

$$V_o = 1000 \text{ V}, R_o = 40 \text{ k}\Omega, I_o = 25 \text{ mA}, f = 3 \text{ GHz}$$

Gap spacing in either cavity  $d = 1 \text{ mm}$

Spacing between the two cavities  $L = 4 \text{ cm}$

Effective shunt impedance, excluding beam load  $R_{sh} = 30 \text{ k}\Omega$

- (i) Find the input gap voltage to give maximum voltage  $V$ .
- (ii) Find the voltage gain, neglecting the beam loading in the output cavity.
- (iii) Find the efficiency of the amplifier, neglecting beam loading.
- (iv) Calculate the beam loading conductance.

4. Attempt any **two** parts of the following : (10×2=20)

- (a) Draw the physical structure and explain principle of operation of IMPATT diode.

An IMPATT diode has the following parameters :

Carrier drift velocity  $V_d = 2 \times 10^7 \text{ cm/sec}$

Drift region length  $L = 6 \text{ }\mu\text{m}$

Maximum operating voltage  $V_{o \max} = 100 \text{ V}$

Maximum operating current  $I_{o \max} = 200 \text{ n A}$

Efficiency  $\eta = 15\%$ , Breakdown voltage  $V_{bd} = 90 \text{ V}$

Calculate :

- (i) maximum CW output power in watts
  - (ii) the resonant frequency in GHz.
- (b) With neat sketch explain microwave characteristics of tunnel diode. Also explain tunneling phenomenon.
- (c) Write short notes on :
- (i) Microwave Bipolar Junction Transistor
  - (ii) Transferred electron devices.
5. Attempt any two parts of the following : **(10×2=20)**
- (a) How Insertion and Attenuation loss of Isolator are measured ? Explain in detail.
  - (b) Explain in detail measurement of antenna characteristics.
  - (c) How frequency of source is measured using microwave test bench ? Explain in detail.